Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material: Ceramic **Overall Length:** Between 0.750 inches and 0.785 inches **Terminal Length:** Between 0.100 inches and 0.165 inches **Overall Height:** 0.200 inches **Overall Width:** Between 0.245 inches and 0.271 inches **Component Name And Quantity:** 13 semiconductor device diode **Mounting Method:** Terminal **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 40.0 reverse voltage, peak all semiconductor **Current Rating Per Characteristic:** 350.00 milliamperes source cutoff current preset all semiconductor Maximum Operating Tempurature Per Measurement Point: 150.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Precious Material And Location:** Terminals option. Gold **Precious Material:** Gold **Terminal Type And Quantity:** 14 pin Shelf Life: N/a Unit Of Measure: Demilitarization: Yes - demil/mli Fiig: A110a0